

Wespack Phase Control Thyristor

Types N2191ML160 to N2191ML180

Development Type No.: NX313ML160-180

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	1600-1800	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	1600-1800	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1600-1800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1500-1900	V

	OTHER RATINGS		MAXIMUM LIMITS	UNITS
I _{T(AV)M}	Maximum average on-state current, T _{sink} =55°C, (note 2)		2191	A
I _{T(AV)M}	Maximum average on-state current. T _{sink} =85°C, (note 2)		1476	A
I _{T(AV)M}	Maximum average on-state current. T _{sink} =85°C, (note 3)		743	A
I _{T(RMS)M}	Nominal RMS on-state current, T _{sink} =25°C, (note 2)		4366	A
I _{T(d.c.)}	D.C. on-state current, T _{sink} =25°C, (note 4)		3685	A
I _{TSM}	Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 5)		34.5	kA
I _{TSM2}	Peak non-repetitive surge t _p =10ms, V _{rm} ≤10V, (note 5)		38.0	kA
I ² t	I ² t capacity for fusing t _p =10ms, V _{rm} =60%V _{RRM} , (note 5)		5.95×10 ⁶	A ² s
I ² t	I ² t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 5)		7.22×10 ⁶	A ² s
(di/dt) _{cr}	Critical rate of rise of on-state current (note 6)	(continuous, 50Hz)	100	A/μs
		(repetitive, 50Hz, 60s)	200	
		(non-repetitive)	400	
V _{RGM}	Peak reverse gate voltage		5	V
P _{G(AV)}	Mean forward gate power		4	W
P _{GM}	Peak forward gate power		30	W
T _{j op}	Operating temperature range		-40 to +125	°C
T _{stg}	Storage temperature range		-40 to +150	°C

Notes:-

- De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- Double side cooled, single phase; 50Hz, 180° half-sinewave.
- Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- Double side cooled.
- Half-sinewave, $125^{\circ}C$ T_j initial.
- $V_D=67\% V_{DRM}$, $I_{TM}=2000A$, $I_{FG}=2A$, $t_r\leq 0.5\mu s$, $T_{case}=125^{\circ}C$.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{TM}	Maximum peak on-state voltage	-	-	1.40	I _{TM} =3000A	V
V _{TM}	Maximum peak on-state voltage	-	-	2.15	I _{TM} =7800A	V
V _{T0}	Threshold voltage	-	-	0.940		V
r _T	Slope resistance	-	-	0.154		mΩ
(dv/dt) _{cr}	Critical rate of rise of off-state voltage	1000	-	-	V _D =80% V _{DRM} , linear ramp, gate o/c	V/μs
I _{DRM}	Peak off-state current	-	-	100	Rated V _{DRM}	mA
I _{RRM}	Peak reverse current	-	-	100	Rated V _{RRM}	mA
V _{GT}	Gate trigger voltage	-	-	3.0	T _j =25°C V _D =10V, I _T =3A	V
I _{GT}	Gate trigger current	-	-	300		mA
V _{GD}	Gate non-trigger voltage	-	-	0.25		V
I _H	Holding current	-	-	1000	T _j =25°C	mA
t _{gd}	Gate-controlled turn-on delay time	-	0.8	2.0	V _D =67% V _{DRM} , I _T =2000A, di/dt=10A/μs, I _{FG} =2A, t _r =0.5μs, T _j =25°C	μs
t _{gt}	Turn-on time	-	1.4	3.0		μs
Q _{rr}	Recovered charge	-	3600	3900	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs, V _r =50V	μC
Q _{ra}	Recovered charge, 50% Chord	-	2150	-		μC
I _{rr}	Reverse recovery current	-	150	-		A
t _{rr}	Reverse recovery time	-	29	-		μs
t _q	Turn-off time	-	350	-	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs, V _r =50V, V _{dr} =80%V _{DRM} , dV _{dr} /dt=20V/μs	μs
		-	600	-	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs, V _r =50V, V _{dr} =80%V _{DRM} , dV _{dr} /dt=200V/μs	
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.018	Double side cooled	K/W
		-	-	0.033	Anode side cooled	K/W
		-	-	0.044	Cathode side cooled	K/W
F	Mounting force	25	-	31	Note 2.	kN
W _t	Weight	-	550	-		g

Notes:-

- 1) Unless otherwise indicated T_j=125°C.
- 2) For other clamp forces, please consult factory.

Curves

Figure 1 – On-state characteristics of Limit device

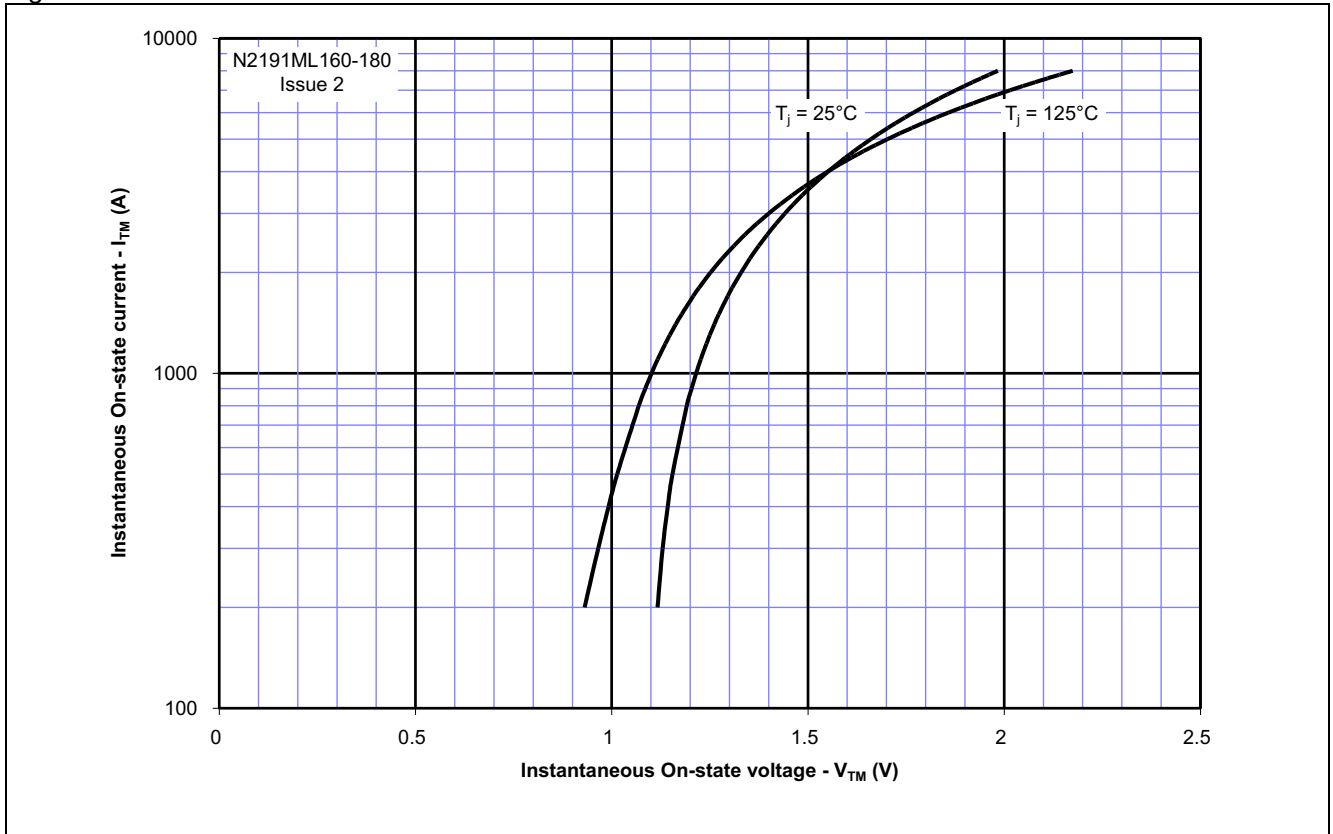


Figure 2 – Transient thermal impedance

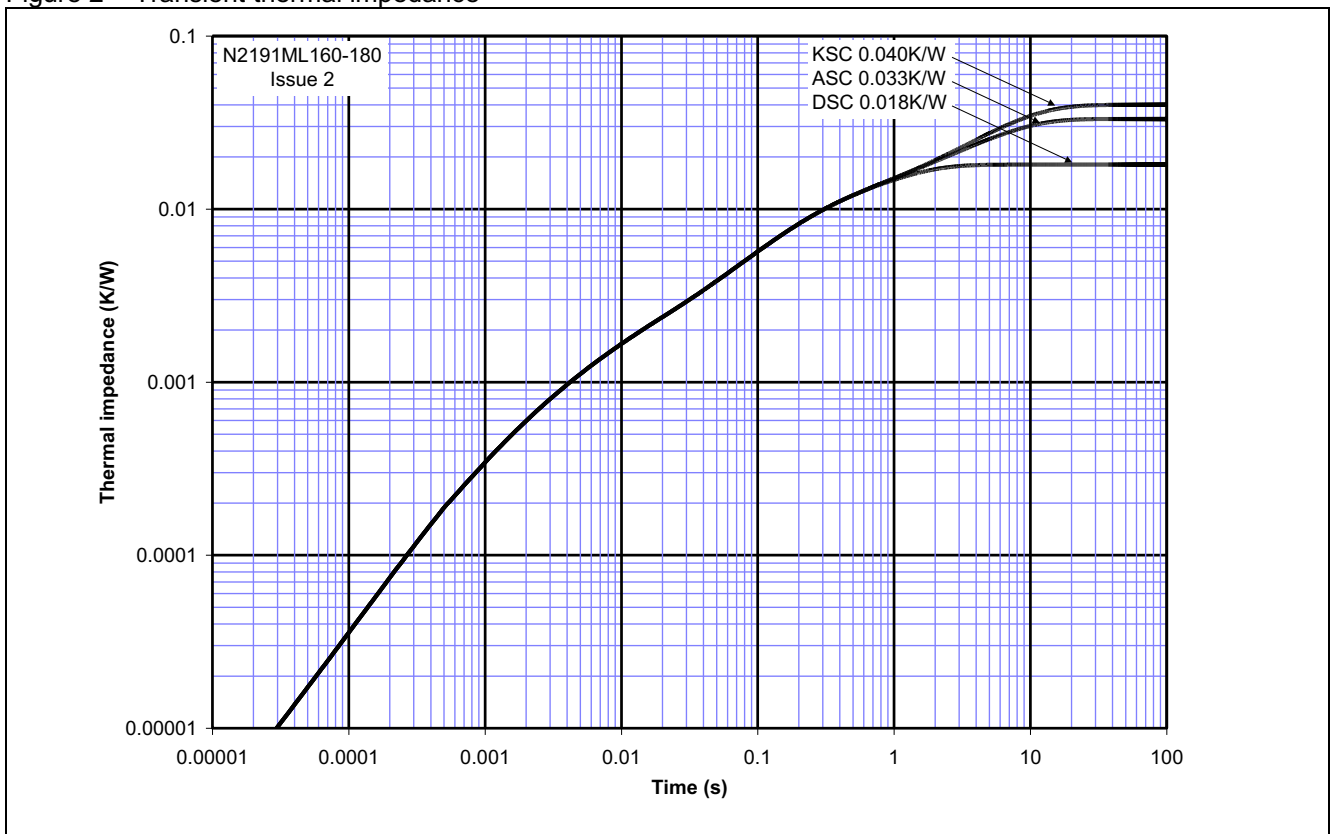
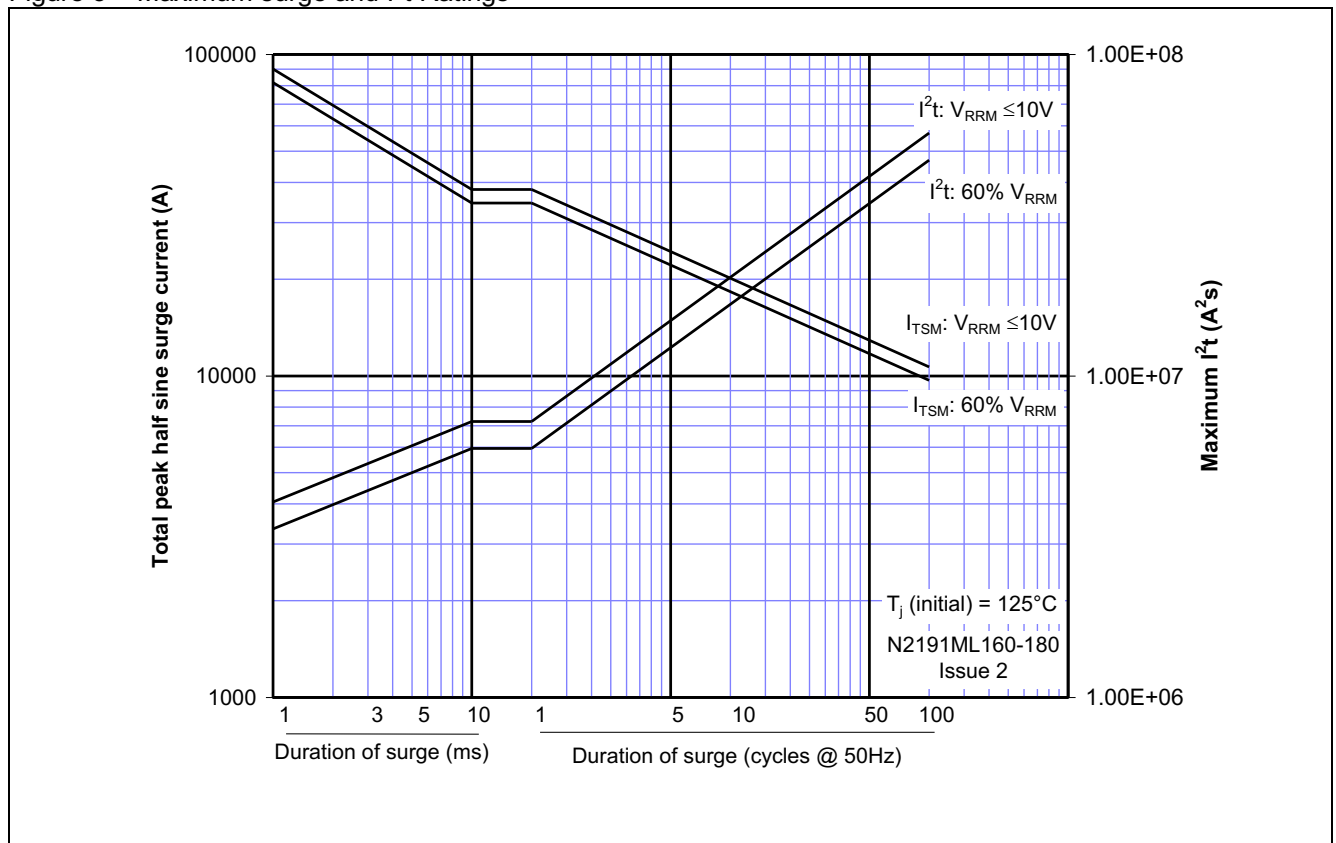
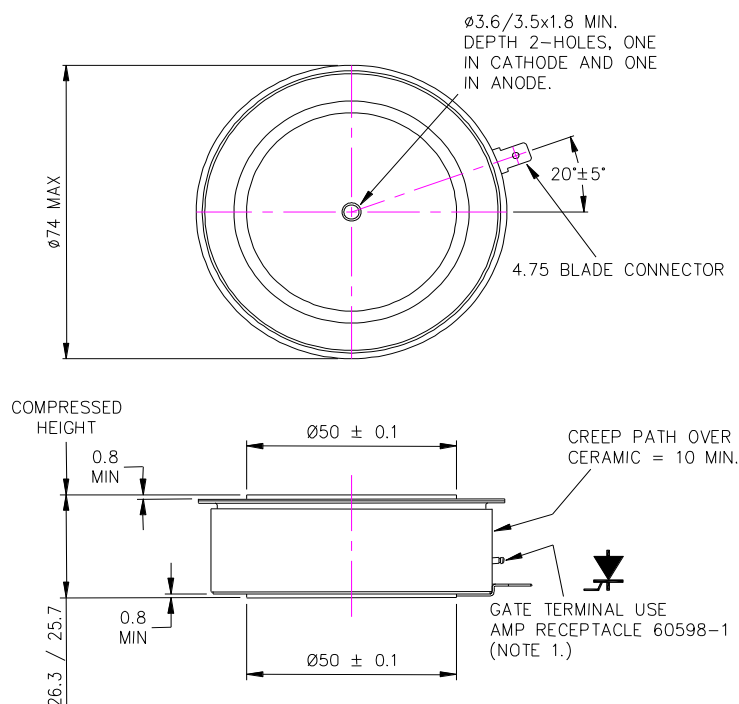


Figure 3 – Maximum surge and I^2t Ratings



Outline Drawing & Ordering Information



101A356

ORDERING INFORMATION

(Please quote 10 digit code as below)

N2191	ML	◆◆	0
Fixed Type Code	Fixed outline code	Voltage code $V_{DRM}/100$ 16-18	Fixed turn-off time code

Order code: N2191ML160 – 1600V V_{DRM} , V_{RRM} , 26mm clamp height capsule.

IXYS Semiconductor GmbH
 Edisonstraße 15
 D-68623 Lampertheim
 Tel: +49 6206 503-0
 Fax: +49 6206 503-627
 E-mail: marcom@ixys.de



IXYS UK Westcode Ltd
 Langley Park Way, Langley Park,
 Chippenham, Wiltshire, SN15 1GE.
 Tel: +44 (0)1249 444524
 Fax: +44 (0)1249 659448
 E-mail: sales@ixysuk.com

IXYS Corporation
 1590 Buckeye Drive
 Milpitas CA 95035-7418
 Tel: +1 (408) 457 9000
 Fax: +1 (408) 496 0670
 E-mail: sales@ixys.net

www.ixysuk.com

www.ixys.com

IXYS Long Beach
 IXYS Long Beach, Inc
 2500 Mira Mar Ave, Long Beach
 CA 90815
 Tel: +1 (562) 296 6584
 Fax: +1 (562) 296 6585
 E-mail: service@ixyslongbeach.com

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors IXYS UK Westcode Ltd.

© IXYS UK Westcode Ltd.

In the interest of product improvement, IXYS UK Westcode reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.



Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.